## PF01412A

# MOS FET Power Amplifier Module for E-GSM Handy Phone

# **HITACHI**

ADE-208-477B (Z) 3rd Edition February 1, 1997

### **Application**

- For GSM class4 890 to 915 MHz
- For 5.5V nominal DC/DC converter use

#### **Features**

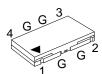
• High gain 3stage amplifier: 0 dBm input

• Lead less thin & Small package: 2 mm Max, 0.2cc

High efficiency: 45% Typ at 3.8 WWide gain control range: 90 dB Typ

### **Pin Arrangement**

• RF-K



1: Pin 2: Vapc

3: Vdd 4: Pout G: GND

### **Absolute Maximum Ratings** (Tc = 25°C)

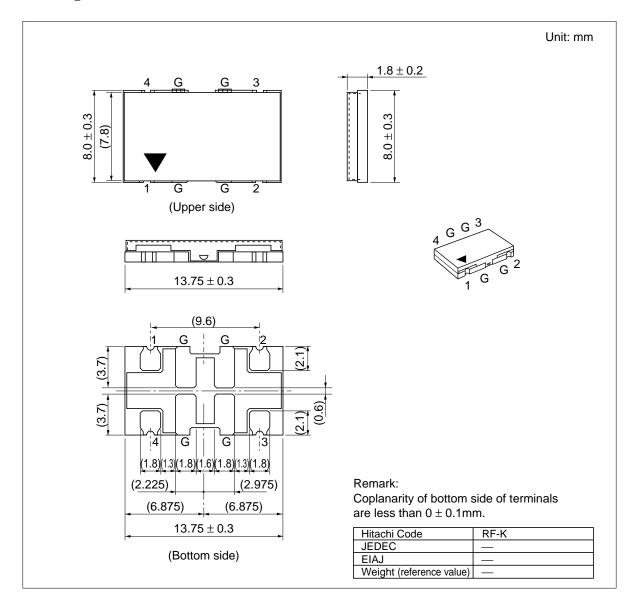
Item	Symbol	Rating	Unit	
Supply voltage	$V_{DD}$	10	V	
Supply current	I <sub>DD</sub>	3	Α	
V <sub>APC</sub> voltage	V <sub>APC</sub>	4	V	
Input power	Pin	10	mW	
Operating case temperature	Tc (op)	-30 to +100	°C	
Storage temperature	Tstg	-30 to +100	°C	
Output power	Pout	6	W	

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### **Electrical Characteristics** (Tc = 25°C)

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Frequency range	f	890	_	915	MHz	
Control voltage range	$V_{APC}$	0.5	_	3.0	V	
Drain cutoff current	I <sub>DS</sub>	_	_	100	μΑ	$V_{DD} = 10 \text{ V}, V_{APC} = 0 \text{ V}$
Total efficiency	$\eta_{\scriptscriptstyleT}$	40	45	_	%	$Pin = 1 \text{ mW}, V_{DD} = 5.5 \text{ V},$
2nd harmonic distortion	2nd H.D.	_	-45	-35	dBc	Pout = 3.8 W, Vapc = controlled
3rd harmonic distortion	3rd H.D.	_	-45	-35	dBc	$R_L = Rg = 50 \Omega$ , $Tc = 25^{\circ}C$
Input VSWR	VSWR (in)	_	1.5	3	_	-
Output power (1)	Pout (1)	3.8	4.5	_	W	$\begin{aligned} &\text{Pin} = 1 \text{ mW, V}_{\text{DD}} = 5.5 \text{ V,} \\ &\text{V}_{\text{APC}} = 3.0 \text{ V, R}_{\text{L}} = \text{Rg} = 50 \Omega, \\ &\text{Tc} = 25^{\circ}\text{C} \end{aligned}$
Output power (2)	Pout (2)	2.5	3.2	_	W	Pin = 1 mW, $V_{DD}$ = 5.0 V, $V_{APC}$ = 3.0 V, $R_{L}$ = $Rg$ = 50 Ω, $Tc$ = $80^{\circ}C$
Isolation	_	_	-50	-40	dBm	Pin = 1 mW, $V_{DD}$ = 5.5 V, $V_{APC}$ = 0.5 V, $R_{L}$ = Rg = 50 Ω, $Tc$ = 25°C
Switching time	tr, tf	_	1	2	μs	Pin = 1 mW, $V_{DD}$ = 5.5 V, Pout = 3.8 W, $R_{L}$ = Rg = 50 Ω, Tc = 25°C
Stability & Load VSWR tolerance	_	No parasitic oscillation & No degradation		_	Pin = 1 mW, $V_{DD}$ = 5 to 6 V, Pout $\leq$ 3.8 W, Vapc $\leq$ 3 V GSM pulse. Rg = 50 $\Omega$ , t = 20 sec., Tc = 25°C, Output VSWR = 6 : 1 All phases	

### **Package Dimensions**



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